BLF178XR; BLF178XRS

Power LDMOS transistor

AMPLEON

Rev. 5 — 1 September 2015

Product data sheet

1. Product profile

1.1 General description

A 1400 W extremely rugged LDMOS power transistor for broadcast and industrial applications in the HF to 128 MHz band.

Table 1. Application information

Test signal	f	V _{DS}	PL	Gp	η _D
	(MHz)	(V)	(W)	(dB)	(%)
CW	108	50	1200	23	80
pulsed RF	108	50	1400	28	72

1.2 Features and benefits

- Typical pulsed performance at frequency of 108 MHz, a supply voltage of 50 V and an I_{Dq} of 40 mA, a t_p of 100 μs with δ of 20 %:
 - ◆ Output power = 1400 W
 - ◆ Power gain = 28 dB
 - ◆ Efficiency = 72 %
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 128 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

2. Pinning information

Table 2. Pinning

IUDIO Z.	9		
Pin	Description	Simplified outline	e Graphic symbol
BLF178XF	R (SOT539A)		
1	drain1		,
2	drain2	1 2	1 1 .∟
3	gate1		⁵ 3
4	gate2	3 4	5
5	source	[1]	4
			' <u></u>
			2 sym117

BLF178XRS	(SOT539B)			
1	drain1			,
2	drain2		1 2	1
3	gate1		5	3
4	gate2		3 4	5
5	source	[1]		2 sym117

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	er Package			
	Name	Description	Version	
BLF178XR	-	flanged balanced LDMOST ceramic package; 2 mounting holes; 4 leads	SOT539A	
BLF178XRS	-	earless flanged balanced LDMOST ceramic package; 4 leads	SOT539B	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	110	V
V_{GS}	gate-source voltage		-6	+11	V
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-	200	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	T _j = 150 °C	[1][2]	0.11	K/W
Z _{th(j-c)}	transient thermal impedance from junction to case	T_j = 150 °C; t_p = 100 μ s; δ = 20 %	[3]	0.033	K/W

- [1] T_i is the junction temperature.
- [2] Rth(j-c) is measured under RF conditions.
- [3] See Figure 1.

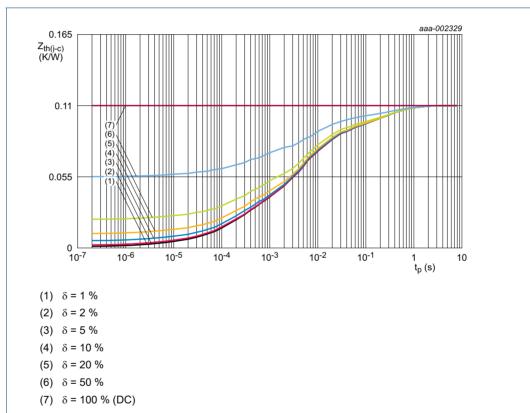


Fig 1. Transient thermal impedance from junction to case as a function of pulse duration

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 5.5 \text{ mA}$	110	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 550 mA	1.25	1.7	2.25	V
V_{GSq}	gate-source quiescent voltage	V_{DS} = 50 V; I_{D} = 20 mA	8.0	1.3	1.8	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}$	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	77	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	280	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 19.25 \text{ A}$	-	0.07	-	Ω

Table 7. AC characteristics

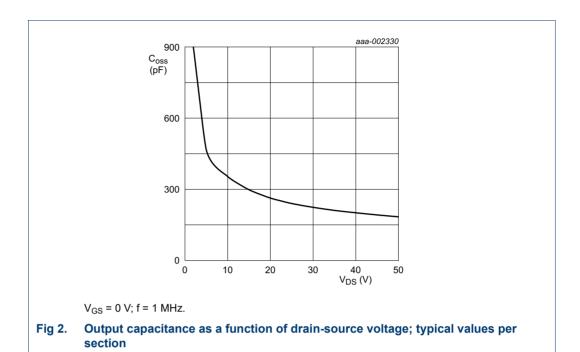
 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{rs}	feedback capacitance	V_{GS} = 0 V; V_{DS} = 50 V; f = 1 MHz	-	5.5	-	pF
C _{iss}	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	414	-	pF
Coss	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	184	-	pF

Table 8. RF characteristics

Test signal: pulsed RF; t_p = 100 μ s; δ = 20 %; f = 108 MHz; RF performance at V_{DS} = 50 V; I_{Dq} = 40 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L} = 1400 \text{ W}$	27	28	-	dB
RLin	input return loss	P _L = 1400 W	-	-15	-11	dB
η_{D}	drain efficiency	P _L = 1400 W	68	72	-	%



7. Test information

7.1 Ruggedness in class-AB operation

The BLF178XR and BLF178XRS are capable of withstanding a load mismatch corresponding to VSWR > 65 : 1 through all phases under the following conditions: $V_{DS} = 50 \text{ V}$; $I_{Dq} = 40 \text{ mA}$; $P_{L} = 1400 \text{ W}$ pulsed; f = 108 MHz.

7.2 Impedance information

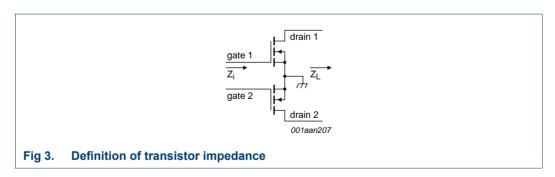
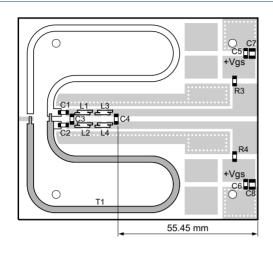


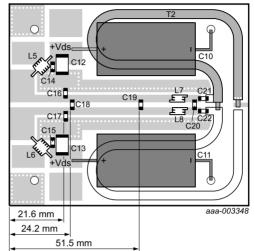
Table 9. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at $V_{DS} = 50 \text{ V}$ and $P_L = 1400 \text{ W}$.

f	Z_{i}	Z L
(MHz)	(Ω)	(Ω)
108	2.35 – j6.06	2.78 + j0.48

7.3 Test circuit





Printed-Circuit Board (PCB): RF 35; ϵ_r = 3.5; thickness = 0.765 mm; thickness copper plating = 35 μ m. See <u>Table 10</u> for a list of components.

Fig 4. Component layout for class-AB production test circuit

Table 10. List of components For test circuit see Figure 4.

Component	Description	Value	Remarks
C1, C2, C5, C6, C14, C15, C21, C22	multilayer ceramic chip capacitor	1 nF	[1]
C3	multilayer ceramic chip capacitor	82 pF	[1]
C4	multilayer ceramic chip capacitor	240 pF	[1]
C7, C8	multilayer ceramic chip capacitor	$4.7~\mu F;50~V$	
C10, C11	electrolytic capacitor	2200 μF ; 63 V	
C12, C13	multilayer ceramic chip capacitor	4.7 μF; 100 V	
C16, C17	multilayer ceramic chip capacitor	120 pF	[1]
C18	multilayer ceramic chip capacitor	82 pF	[1]
C19	multilayer ceramic chip capacitor	110 pF	[1]
C20	multilayer ceramic chip capacitor	56 pF	[1]
L1, L2, L3, L4	1.5 turn 0.8 mm copper wire	D = 3 mm; length = 2 mm	
L5, L6	5 turn 0.8 mm copper wire	D = 3 mm; length = 4.5 mm	
L7, L8	2.5 turn 0.8 mm copper wire	D = 3 mm; length = 3 mm	
R3, R4	SMD resistor	9.1 Ω	1206
T1	semi rigid coax	25 $Ω$; 160 mm	UT-090C-25
T2	semi rigid coax	25 $Ω$; 160 mm	UT-141C-25

^[1] American Technical Ceramics type 800B or capacitor of same quality.

7.4 Graphical data

The following figures are measured in a class-AB production test circuit.

7.4.1 1-Tone CW pulsed

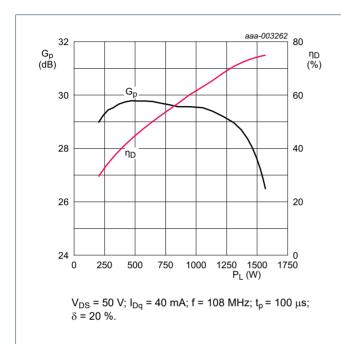
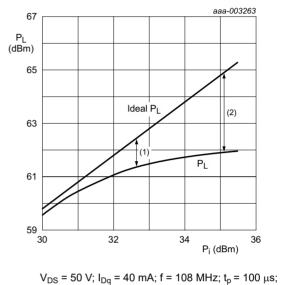


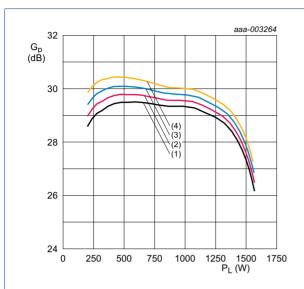
Fig 5. Power gain and drain efficiency as function of output power; typical values



 $V_{DS} = 50 \text{ V}; I_{Dq} = 40 \text{ mA}; f = 108 \text{ MHz}; t_p = 100 \text{ }\mu\text{s}; \delta = 20 \text{ }\%.$

- (1) $P_{L(1dB)} = 61.3 \text{ dBm } (1350 \text{ W})$
- (2) $P_{L(3dB)} = 61.9 \text{ dBm } (1550 \text{ W})$

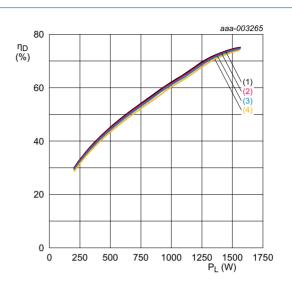
Fig 6. Output power as a function of input power; typical values



 V_{DS} = 50 V; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $I_{Dq} = 20 \text{ mA}$
- (2) $I_{Dq} = 40 \text{ mA}$
- (3) $I_{Dq} = 80 \text{ mA}$
- (4) $I_{Dq} = 160 \text{ mA}$

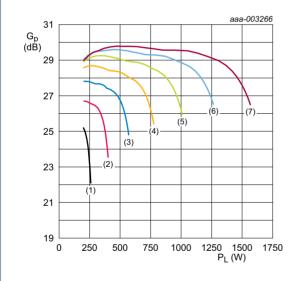
Fig 7. Power gain as a function of output power; typical values



 $V_{DS} = 50 \text{ V}$; f = 108 MHz; $t_p = 100 \text{ } \mu\text{s}$; $\delta = 20 \text{ } \%$.

- (1) $I_{Dq} = 20 \text{ mA}$
- (2) $I_{Dq} = 40 \text{ mA}$
- (3) $I_{Dq} = 80 \text{ mA}$
- (4) $I_{Dq} = 160 \text{ mA}$

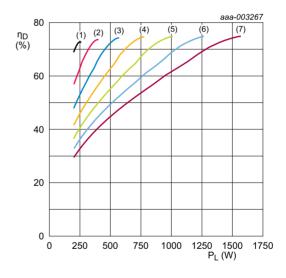
Fig 8. Drain efficiency as a function of output power; typical values



 I_{Dq} = 40 mA; f = 108 MHz; t_p = 100 $\mu s;~\delta$ = 20 %.

- (1) $V_{DS} = 20 \text{ V}$
- (2) $V_{DS} = 25 V$
- (3) $V_{DS} = 30 \text{ V}$
- (4) $V_{DS} = 35 \text{ V}$
- (5) $V_{DS} = 40 \text{ V}$
- (6) $V_{DS} = 45 \text{ V}$
- (7) $V_{DS} = 50 \text{ V}$

Fig 9. Power gain as a function of output power; typical values



 I_{Dq} = 40 mA; f = 108 MHz; t_p = 100 μ s; δ = 20 %.

- (1) $V_{DS} = 20 \text{ V}$
- (2) $V_{DS} = 25 V$
- (3) $V_{DS} = 30 \text{ V}$
- (4) $V_{DS} = 35 V$
- (5) $V_{DS} = 40 \text{ V}$
- (6) V_{DS} = 45 V
- (7) $V_{DS} = 50 \text{ V}$

Fig 10. Drain efficiency as a function of output power; typical values

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8. Package outline

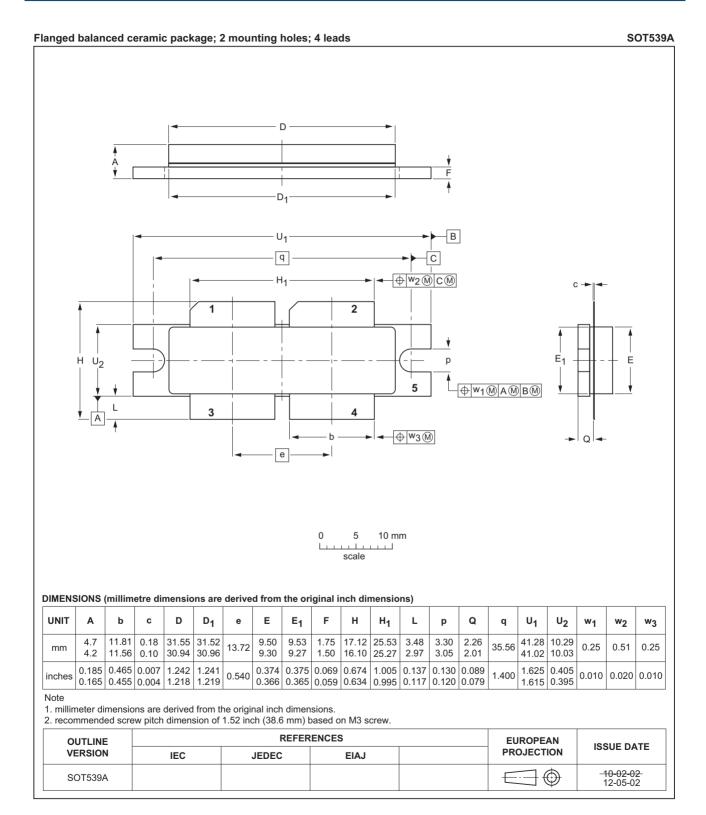


Fig 11. Package outline SOT539A

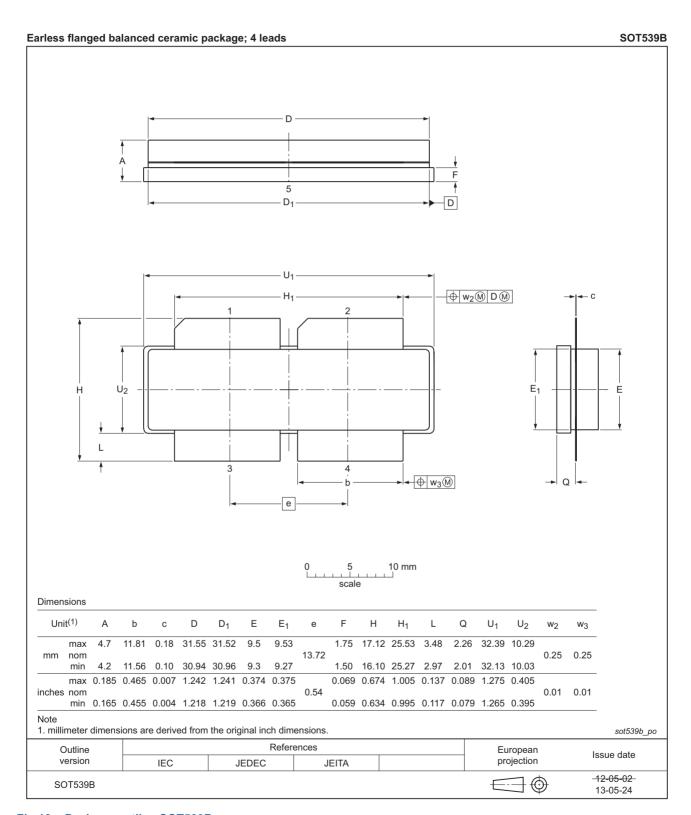


Fig 12. Package outline SOT539B

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 11. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF178XR_BLF178XRS#5	20150901	Product data sheet	-	BLF178XR_BLF178XRS v.4	
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 				
	 Legal texts have been adapted to the new company name where appropriate. 				
BLF178XR_BLF178XRS v.4	<tbd></tbd>	Product data sheet	-	BLF178XR_BLF178XRS v.3	
BLF178XR_BLF178XRS v.3	20120625	Product data sheet	-	BLF178XR_BLF178XRS v.2	
BLF178XR_BLF178XRS v.2	20120515	Preliminary data sheet	-	BLF178XR_BLF178XRS v.1	
BLF178XR_BLF178XRS v.1	20120130	Objective data sheet	-	-	

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Document status[1][2]	Product status[3]	Definition
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Product [short] data sheet	Production	This document contains the product specification.

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